

DOCKET NO.: 239120US0DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
KAZUHITO MATSUKAWA : ATTN: APPLICATION DIVISION  
SERIAL NO: NEW U.S. PCT APPLN. :  
(Divisional of 09/668,368)  
FILED: HEREWITH :  
FOR: SEMICONDUCTOR SUBSTRATE, :  
SEMICONDUCTOR DEVICE, AND  
MANUFACTURING METHOD  
THEREOF

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS,  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Discussion of the Amendment** begins on page 4 of this paper.

**Remarks** begins on page 5 of this paper.